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STMicroelectronics STTH30S06W

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STTH30S06

Turbo 2 ultrafast high voltage rectifier

Datasheet - production data

Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- ECOPACK[®]2 compliant component

Description

The STTH30S06, which uses ST turbo 2, 600 V technology, is especially suited for use in switching power supplies and industrial applications, as rectification and continuous mode PCF boost diode.

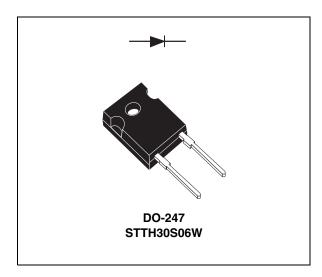


Table 1. Device summary

Symbol	Value	
I _{F(AV)}	30 A	
V _{RRM}	600 V	
t _{rr} (max)	50 ns	
T _j	-40 to +175 °C	
V _F (typ)	1.75 V	



Characteristics STTH30S06

1 Characteristics

Table 2. Absolute ratings (limiting values, at 25 °C, unless otherwise specified)

Symbol	Paramete	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	600	V	
I _{F(RMS)}	Forward rms current	64	Α	
I _{F(AV)}	Average forward current, δ = 0.5	T _c = 65 °C	30	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		180	Α
T _{stg}	Storage temperature range	-65 to + 175	°C	
T _j	Maximum operating junction temperat	-40 to + 175	°C	

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit	
R _{th(j-c)}	Junction to case		1.25	°C / W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _B ⁽¹⁾	L (1) Bayana laskana aymant		V _R = V _{RRM}			50	μА
I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C			50	500		
V _F ⁽²⁾	V (2) Forward voltage drap	T _j = 25 °C	I _F = 30 A			3.6	V
V _F · · · · · · · · · · · · · · · · · · ·	Forward voltage drop	T _j = 125 °C			1.75	2.2	V

^{1.} Pulse test: tp = 5 ms, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 1.45 \text{ x } I_{F(AV)} + 0.025 I_{F}^{2}_{(RMS)}$$

Table 5. Dynamic electrical characteristics

Symbol	Parameter	Test conditions			Тур	Max.	Unit
I _{RM}	Reverse recovery current	T. – 125 °C	$I_F = 30 \text{ A}, V_R = 400 \text{ V}$ $dI_F/dt = -100 \text{ A/}\mu\text{s}$		4	5.5	Α
S _{factor}	Softness factor	1j = 125 C	$dI_F/dt = -100 A/\mu s$		0.35		
t	t _{rr} Reverse recovery time	T _j = 25 °C	$I_F = 1 A, V_R = 30 V$ $dI_F/dt = -50 A/\mu s$			50	
rr			I _F = 0.5 A, I _{rr} = 0.25 A, I _R = 1 A			30	ns
t _{fr}	Forward recovery time		$I_F = 30 \text{ A}, V_{FR} = 2.6 \text{ V}$ $dI_F/dt = 300 \text{ A/}\mu\text{s}$			100	
V _{FP}	Forward recovery voltage				3.7		V

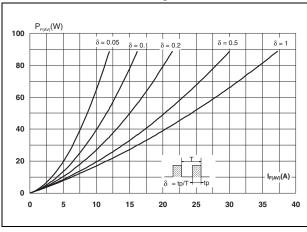
2/7 Doc ID 023787 Rev 1

^{2.} Pulse test: tp = 380 μ s, δ < 2%



STTH30S06 Characteristics

Figure 1. Average forward power dissipation Figure 2. Forward voltage drop versus versus average forward current forward current



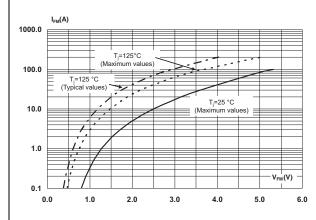
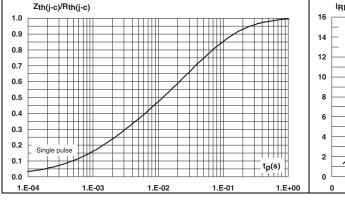


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)



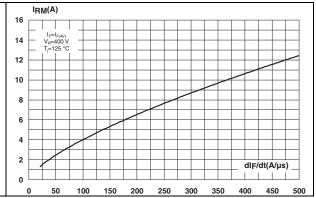
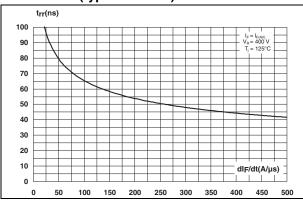
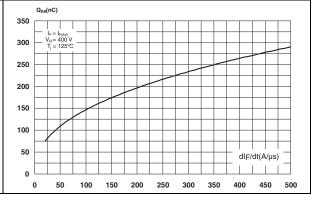


Figure 5. Reverse recovery time versus dl_F/dt Figure 6. Reverse recovery charges versus dl_F/dt (typical values)



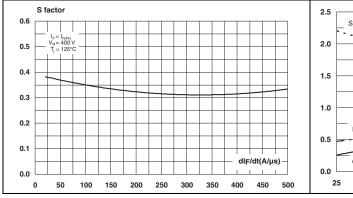




Characteristics STTH30S06

Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values)

Figure 8. Relative variation of dynamic parameters versus junction temperature



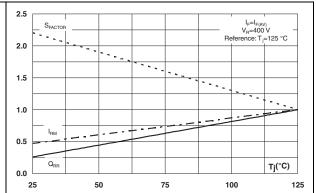
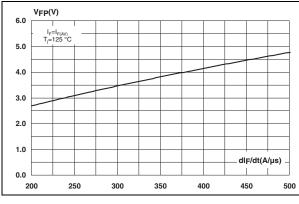


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values)

Figure 10. Forward recovery time versus dI_F/dt (typical values)



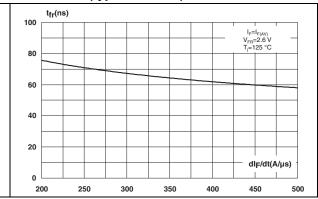
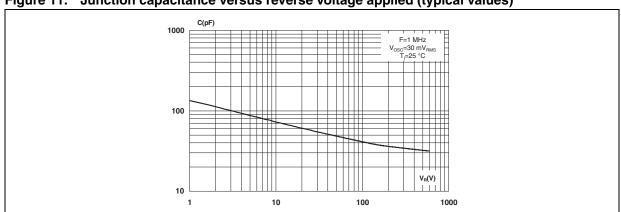


Figure 11. Junction capacitance versus reverse voltage applied (typical values)



4/7 Doc ID 023787 Rev 1



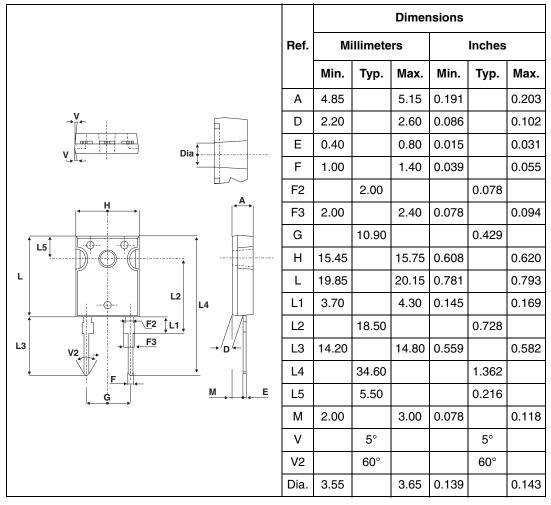
STTH30S06 Package information

2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N⋅m (1.0 N⋅m maximum)

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Table 6. DO-247 dimensions







Ordering information

STTH30S06

3 Ordering information

Table 7. Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTH30S06W	STTH30S06W	DO-247	4.40 g	30	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
17-Jan-2013	1	First issue.

6/7 Doc ID 023787 Rev 1



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